TOSHIBA Field Effect Transistor Silicon N Channel Type

2SK2037

High Speed Switching Applications Analog Switching Applications

• High input impedance.

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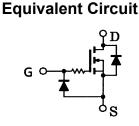
- Low gate threshold voltage: $V_{th} = 0.5 \sim 1.5 \text{ V}$
- Excellent switching times: $t_{on} = 0.28 \ \mu s \ (typ.)$

toff = 0.34 μs (typ.)

- Small package.
- Enhancement-mode

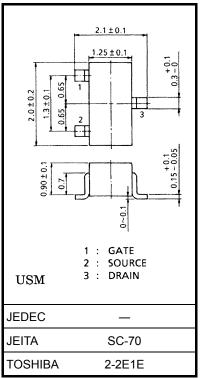
Marking





Absolute Maximum Ratings (Ta = 25°C)

Characteristics	Symbol	Rating	Unit
Drain-source voltage	V _{DS}	20	V
Gate-source voltage	V _{GSS}	10	V
DC drain current	I _D	100	mA
Drain power dissipation	PD	100	mW
Channel temperature	T _{ch}	150	°C
Storage temperature range	T _{stg}	-55~150	°C



Weight: 0.006 g (typ.)

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

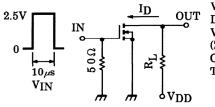
Note: This transistor is electrostatic sensitive device. Please handle with caution.

Unit: mm

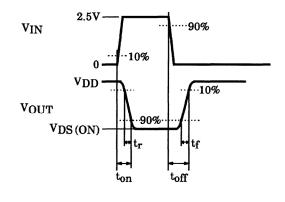
Electrical Characteristics (Ta = 25°C)

Characteristics		Symbol	Test Condition	Min	Тур.	Max	Unit
Gate leakage current		I _{GSS}	$V_{GS} = 10 \text{ V}, \text{ V}_{DS} = 0$	_		1	μA
Drain-source break	kdown voltage	V (BR) DSS	$I_D = 100 \ \mu A, \ V_{GS} = 0$	20	_	_	V
Drain cut-off curren	nt	I _{DSS}	$V_{DS} = 20 V, V_{GS} = 0$	_	_	1	μA
Gate threshold vol	tage	V _{th}	$V_{DS} = 3 \text{ V}, \text{ I}_{D} = 0.1 \text{ mA}$	0.5	_	1.5	V
Forward transfer a	dmittance	Y _{fs}	$V_{DS} = 3 \text{ V}, \text{ I}_{D} = 10 \text{ mA}$	35	62	_	mS
Drain-source ON r	esistance	R _{DS (ON)}	$I_D = 10$ mA, $V_{GS} = 2.5$ V	_	3.5	6	Ω
Input capacitance		C _{iss}	$V_{DS} = 3 V, V_{GS} = 0, f = 1 MHz$	_	14		pF
Reverse transfer capacitance		C _{rss}	$V_{DS} = 3 V, V_{GS} = 0, f = 1 MHz$	_	5.3		pF
Output capacitance		C _{oss}	$V_{DS} = 3 V, V_{GS} = 0, f = 1 MHz$	_	16		pF
Switching time	Turn-on time	t _{on}	$V_{DD} = 3 \text{ V}, I_D = 10 \text{ mA}$ $V_{GS} = 0~2.5 \text{ V}$	_	0.28		
	Turn-off time	t _{off}	$V_{DD} = 3 \text{ V}, I_D = 10 \text{ mA}$ $V_{GS} = 0$ ~2.5 V		0.34	_	μS

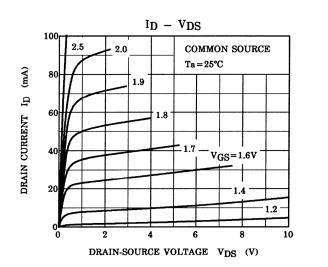
Switching Time Test Circuit

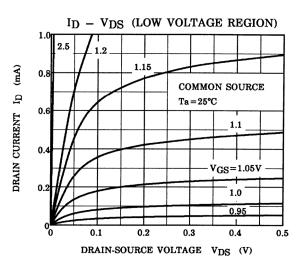


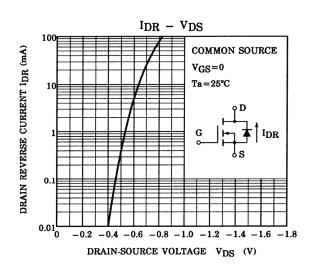
 $\begin{array}{l} V_{DD}{=}\,3V\\ D.U.{\leq}\,1\%\\ V_{IN}:t_r,\,t_f{<}5ns\\ (Z_{out}{=}\,50\Omega)\\ COMMON\ SOURCE\\ Ta{=}\,25^\circ C \end{array}$

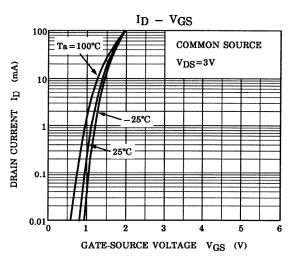


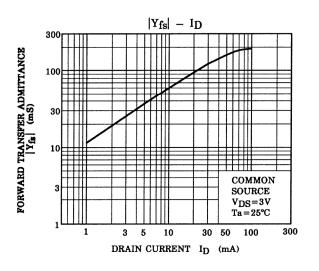
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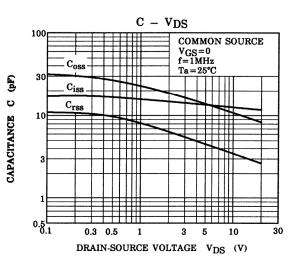




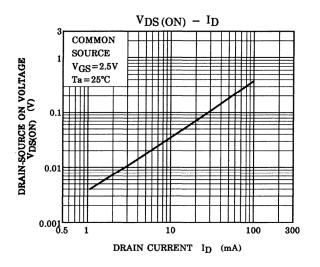


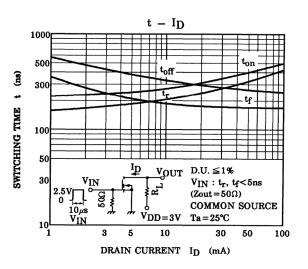


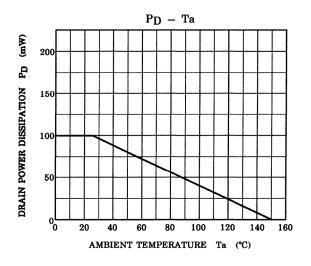




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20070701-EN GENERAL

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